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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Not For New Designs
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	24MHz
Connectivity	I ² C, IrDA, LINbus, SPI, UART/USART
Peripherals	DMA, PDR, POR, PVD, PWM, Temp Sensor, WDT
Number of I/O	80
Program Memory Size	384KB (384K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	2V ~ 3.6V
Data Converters	A/D 16x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32f100vdt6

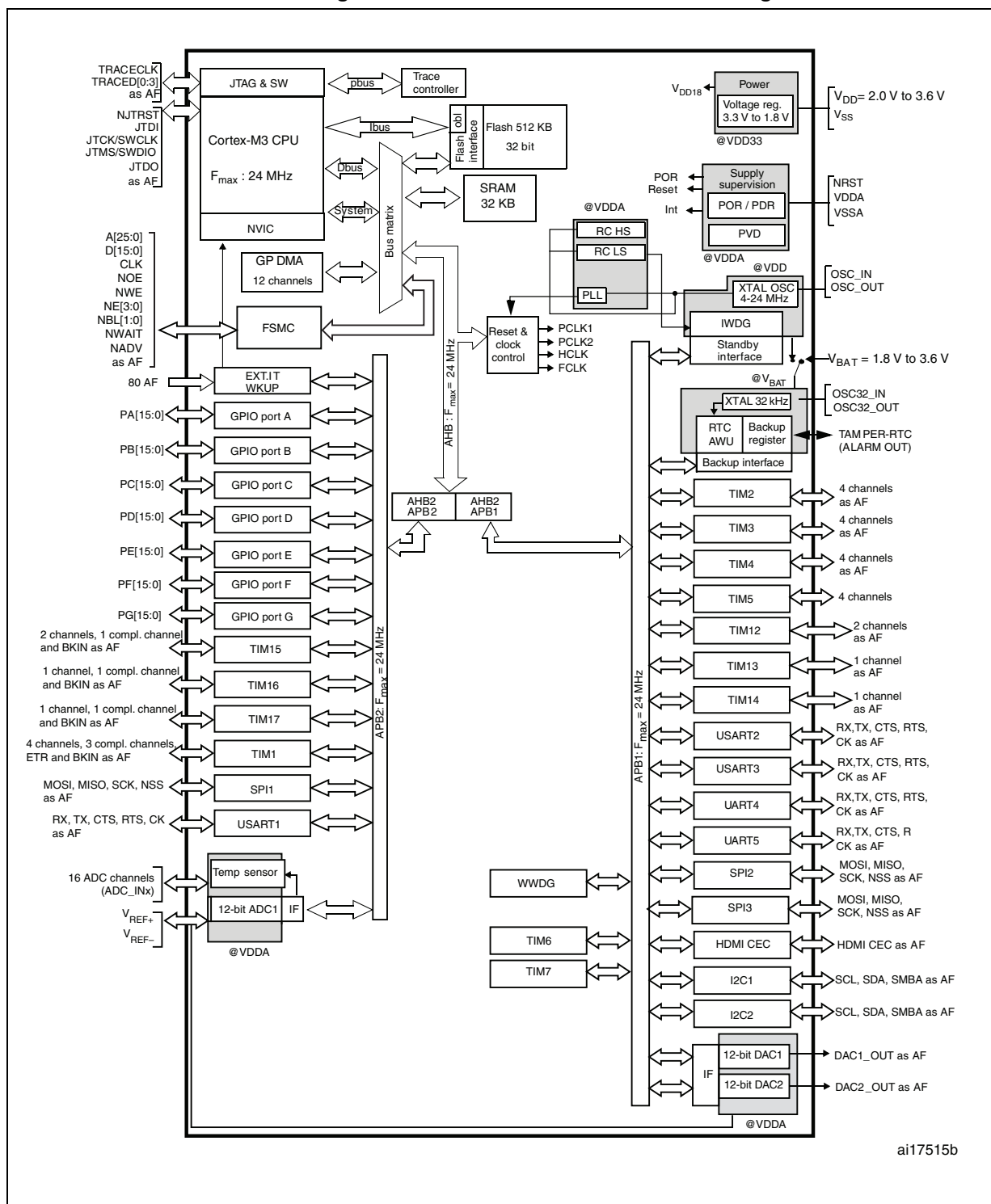
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Figure 1. STM32F100xx value line block diagram



1. AF = alternate function on I/O port pin.
2. $T_A = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ (junction temperature up to $105\text{ }^{\circ}\text{C}$) or $T_A = -40\text{ }^{\circ}\text{C}$ to $+105\text{ }^{\circ}\text{C}$ (junction temperature up to $125\text{ }^{\circ}\text{C}$).

2.2 Overview

2.2.1 ARM® Cortex®-M3 core with embedded Flash and SRAM

The ARM Cortex®-M3 processor is the latest generation of ARM processors for embedded systems. It has been developed to provide a low-cost platform that meets the needs of MCU implementation, with a reduced pin count and low-power consumption, while delivering outstanding computational performance and an advanced system response to interrupts.

The ARM Cortex®-M3 32-bit RISC processor features exceptional code-efficiency, delivering the high-performance expected from an ARM core in the memory size usually associated with 8- and 16-bit devices.

The STM32F100xx value line family having an embedded ARM core, is therefore compatible with all ARM tools and software.

2.2.2 Embedded Flash memory

Up to 512 Kbytes of embedded Flash memory is available for storing programs and data.

2.2.3 CRC (cyclic redundancy check) calculation unit

The CRC (cyclic redundancy check) calculation unit is used to get a CRC code from a 32-bit data word and a fixed generator polynomial.

Among other applications, CRC-based techniques are used to verify data transmission or storage integrity. In the scope of the EN/IEC 60335-1 standard, they offer a means of verifying the Flash memory integrity. The CRC calculation unit helps compute a signature of the software during runtime, to be compared with a reference signature generated at link-time and stored at a given memory location.

2.2.4 Embedded SRAM

Up to 32 Kbytes of embedded SRAM accessed (read/write) at CPU clock speed with 0 wait states.

2.2.5 FSMC (flexible static memory controller)

The FSMC is embedded in the high-density value line family. It has four Chip Select outputs supporting the following modes: SRAM, PSRAM, and NOR.

Functionality overview:

- The three FSMC interrupt lines are ORed in order to be connected to the NVIC
- No read FIFO
- Code execution from external memory
- No boot capability
- The targeted frequency is HCLK/2, so external access is at 12 MHz when HCLK is at 24 MHz

2.2.6 LCD parallel interface

The FSMC can be configured to interface seamlessly with most graphic LCD controllers. It supports the Intel 8080 and Motorola 6800 modes, and is flexible enough to adapt to

HDMI (high-definition multimedia interface) consumer electronics control (CEC)

The STM32F100xx value line embeds a HDMI-CEC controller that provides hardware support of consumer electronics control (CEC) (Appendix supplement 1 to the HDMI standard).

This protocol provides high-level control functions between all audiovisual products in an environment. It is specified to operate at low speeds with minimum processing and memory overhead.

2.2.22 GPIOs (general-purpose inputs/outputs)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain), as input (with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions. All GPIOs are high current capable.

The I/Os alternate function configuration can be locked if needed following a specific sequence in order to avoid spurious writing to the I/Os registers.

2.2.23 Remap capability

This feature allows the use of a maximum number of peripherals in a given application. Indeed, alternate functions are available not only on the default pins but also on other specific pins onto which they are remappable. This has the advantage of making board design and port usage much more flexible.

For details refer to [Table 4: High-density STM32F100xx pin definitions](#); it shows the list of remappable alternate functions and the pins onto which they can be remapped. See the STM32F100xx reference manual for software considerations.

2.2.24 ADC (analog-to-digital converter)

The 12-bit analog to digital converter has up to 16 external channels and performs conversions in single-shot or scan modes. In scan mode, automatic conversion is performed on a selected group of analog inputs.

The ADC can be served by the DMA controller.

An analog watchdog feature allows very precise monitoring of the converted voltage of one, some or all selected channels. An interrupt is generated when the converted voltage is outside the programmed thresholds.

2.2.25 DAC (digital-to-analog converter)

The two 12-bit buffered DAC channels can be used to convert two digital signals into two analog voltage signal outputs. The chosen design structure is composed of integrated resistor strings and an amplifier in noninverting configuration.

Table 5. FSMC pin definition (continued)

Pins	FSMC		LQFP100 ⁽¹⁾
	NOR/PSRAM/SRAM	NOR/PSRAM Mux	
PG10	NE3	NE3	-
PG11	-	-	-
PG12	NE4	NE4	-
PG13	A24	A24	-
PG14	A25	A25	-
PB7	NADV	NADV	Yes
PE0	NBL0	NBL0	Yes
PE1	NBL1	NBL1	Yes

1. Ports F and G are not available in devices delivered in 100-pin packages.

Figure 7. Pin loading conditions

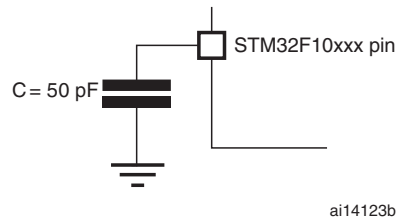
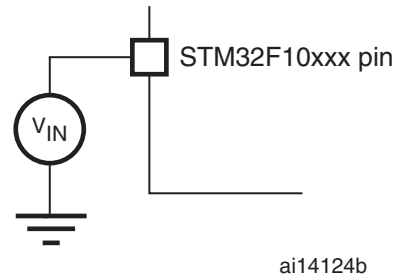
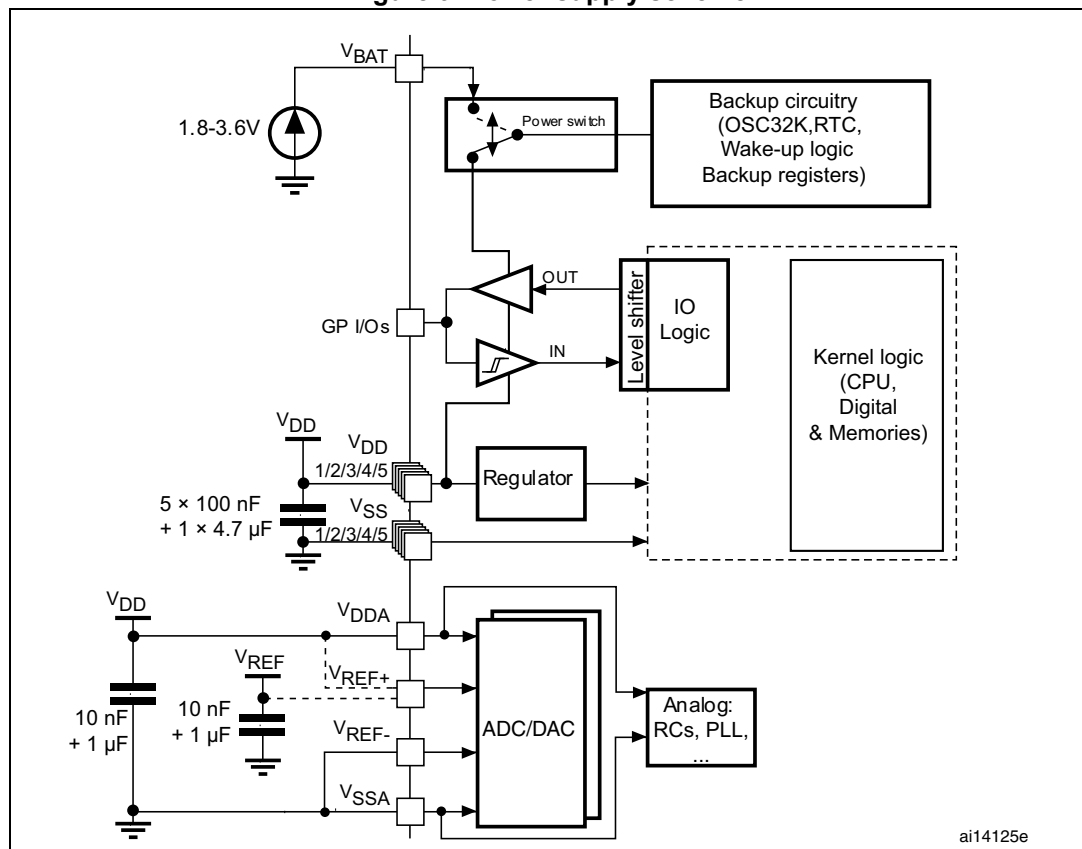


Figure 8. Pin input voltage



5.1.6 Power supply scheme

Figure 9. Power supply scheme



Caution: In [Figure 9](#), the 4.7 μF capacitor must be connected to V_{DD3}.

5.3.3 Embedded reset and power control block characteristics

The parameters given in [Table 11](#) are derived from tests performed under the ambient temperature and V_{DD} supply voltage conditions summarized in [Table 9](#).

Table 11. Embedded reset and power control block characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{PVD}	Programmable voltage detector level selection	PLS[2:0]=000 (rising edge)	2.1	2.18	2.26	V
		PLS[2:0]=000 (falling edge)	2	2.08	2.16	V
		PLS[2:0]=001 (rising edge)	2.19	2.28	2.37	V
		PLS[2:0]=001 (falling edge)	2.09	2.18	2.27	V
		PLS[2:0]=010 (rising edge)	2.28	2.38	2.48	V
		PLS[2:0]=010 (falling edge)	2.18	2.28	2.38	V
		PLS[2:0]=011 (rising edge)	2.38	2.48	2.58	V
		PLS[2:0]=011 (falling edge)	2.28	2.38	2.48	V
		PLS[2:0]=100 (rising edge)	2.47	2.58	2.69	V
		PLS[2:0]=100 (falling edge)	2.37	2.48	2.59	V
		PLS[2:0]=101 (rising edge)	2.57	2.68	2.79	V
		PLS[2:0]=101 (falling edge)	2.47	2.58	2.69	V
		PLS[2:0]=110 (rising edge)	2.66	2.78	2.9	V
		PLS[2:0]=110 (falling edge)	2.56	2.68	2.8	V
		PLS[2:0]=111 (rising edge)	2.76	2.88	3	V
		PLS[2:0]=111 (falling edge)	2.66	2.78	2.9	V
$V_{PVDhyst}^{(2)}$	PVD hysteresis	-	-	100	-	mV
$V_{POR/PDR}$	Power on/power down reset threshold	Falling edge	1.8 ⁽¹⁾	1.88	1.96	V
		Rising edge	1.84	1.92	2.0	V
$V_{PDRhyst}^{(2)}$	PDR hysteresis	-	-	40	-	mV
$t_{RSTTEMPO}^{(2)}$	Reset temporization	-	1.5	2.5	4.5	ms

1. The product behavior is guaranteed by design down to the minimum $V_{POR/PDR}$ value.

2. Guaranteed by design, not tested in production.

Table 19. Peripheral current consumption (continued)

Peripheral		Typical consumption at 25 °C	Unit
APB1 (up to 24 MHz)	APB1-Bridge	3.75	μA/MHz
	TIM2	17.08	
	TIM3	17.50	
	TIM4	17.08	
	TIM5	17.08	
	TIM6	4.58	
	TIM7	4.17	
	TIM12	10.42	
	TIM13	7.08	
	TIM14	7.08	
	SPI2/I2S2	4.58	
	SPI3/I2S3	4.58	
	USART2	12.08	
	USART3	12.08	
	UART4	11.25	
	UART5	10.83	
	I2C1	10.42	
	I2C2	10.42	
	CEC	5.42	
	DAC ⁽²⁾	7.92	
	WWDG	2.92	
	PWR	1.25	
	BKP	2.08	
	IWDG	3.33	

Figure 20. Synchronous multiplexed PSRAM write timings

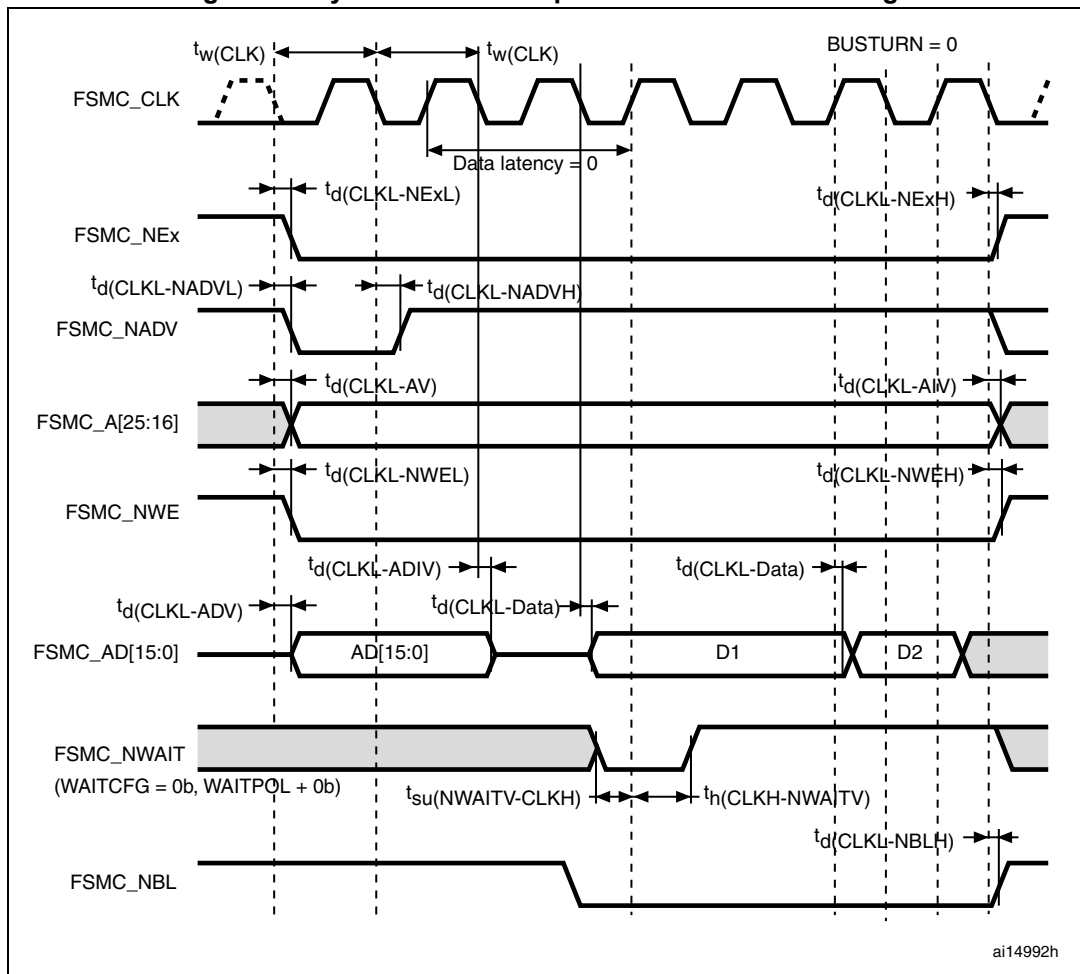


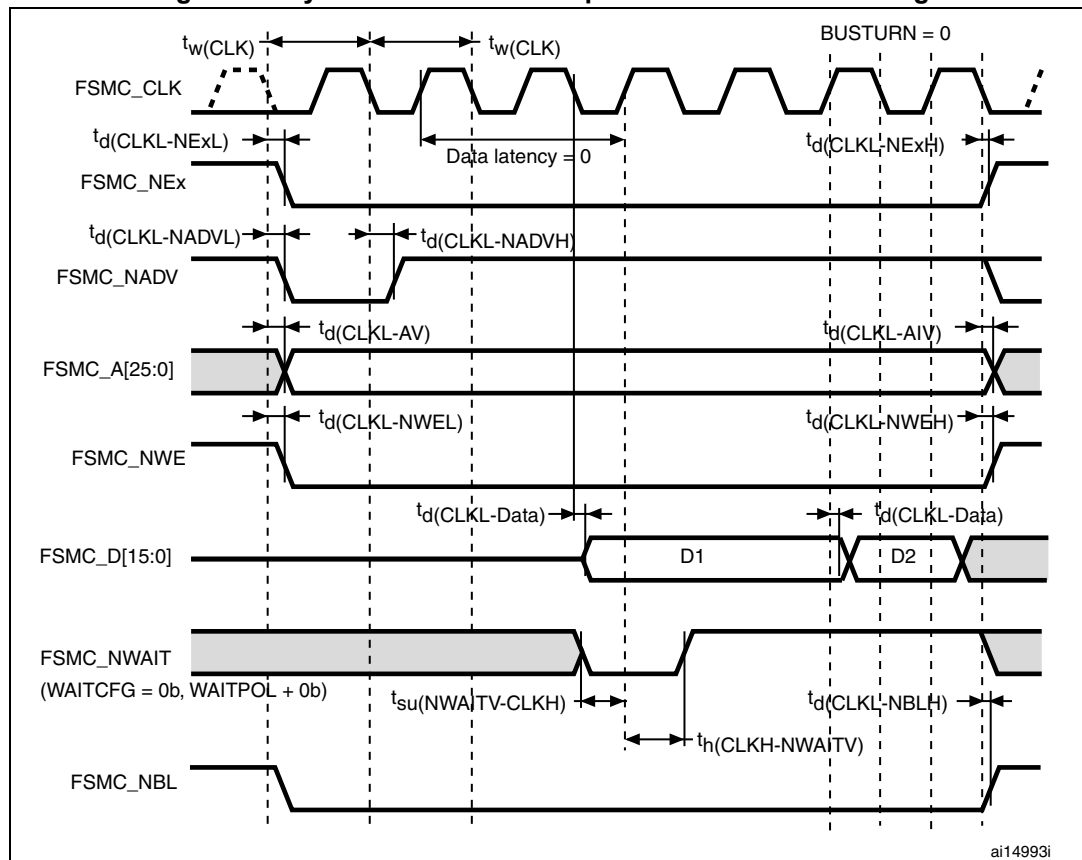
Table 35. Synchronous multiplexed PSRAM write timings⁽¹⁾⁽²⁾

Symbol	Parameter	Min	Max	Unit
$t_{w(CLK)}$	FSMC_CLK period	27.7	-	ns
$t_{d(CLKL-NExL)}$	FSMC_CLK low to FSMC_Nex low (x = 0...2)	-	2	ns
$t_{d(CLKL-NExH)}$	FSMC_CLK low to FSMC_NEx high (x = 0...2)	2	-	ns
$t_{d(CLKL-NADV_L)}$	FSMC_CLK low to FSMC_NADV low	-	4	ns
$t_{d(CLKL-NADV_H)}$	FSMC_CLK low to FSMC_NADV high	5	-	ns
$t_{d(CLKL-AV)}$	FSMC_CLK low to FSMC_Ax valid (x = 16...25)	-	0	ns
$t_{d(CLKL-AIV)}$	FSMC_CLK low to FSMC_Ax invalid (x = 16...25)	2	-	ns
$t_{d(CLKL-NWEL)}$	FSMC_CLK low to FSMC_NWE low	-	1	ns
$t_{d(CLKL-NWEH)}$	FSMC_CLK low to FSMC_NWE high	1	-	ns
$t_{d(CLKL-ADV)}$	FSMC_CLK low to FSMC_AD[15:0] valid	-	12	ns
$t_{d(CLKL-ADIV)}$	FSMC_CLK low to FSMC_AD[15:0] invalid	3	-	ns
$t_{d(CLKL-Data)}$	FSMC_A/D[15:0] valid after FSMC_CLK low	-	6	ns
$t_{su(NWAITV-CLKH)}$	FSMC_NWAIT valid before FSMC_CLK high	7	-	ns
$t_h(CLKH-NWAITV)$	FSMC_NWAIT valid after FSMC_CLK high	2	-	ns
$t_{d(CLKL-NBLH)}$	FSMC_CLK low to FSMC_NBL high	1	-	ns

1. $C_L = 15$ pF.

2. Preliminary values

Figure 22. Synchronous non-multiplexed PSRAM write timings

Table 37. Synchronous non-multiplexed PSRAM write timings⁽¹⁾⁽²⁾

Symbol	Parameter	Min	Max	Unit
$t_{w(CLK)}$	FSMC_CLK period	27.7	-	ns
$t_{d(CLKL-NExL)}$	FSMC_CLK low to FSMC_NEx low (x = 0...2)	-	2	ns
$t_{d(CLKL-NExH)}$	FSMC_CLK low to FSMC_NEx high (x = 0...2)	2	-	ns
$t_{d(CLKL-NADV)}$	FSMC_CLK low to FSMC_NADV low	-	4	ns
$t_{d(CLKL-NADVH)}$	FSMC_CLK low to FSMC_NADV high	5	-	ns
$t_{d(CLKL-AV)}$	FSMC_CLK low to FSMC_Ax valid (x = 16...25)	-	0	ns
$t_{d(CLKL-AIV)}$	FSMC_CLK low to FSMC_Ax invalid (x = 16...25)	2	-	ns
$t_{d(CLKL-NWEL)}$	FSMC_CLK low to FSMC_NWE low	-	1	ns
$t_{d(CLKL-NWEH)}$	FSMC_CLK low to FSMC_NWE high	1	-	ns
$t_{d(CLKL-Data)}$	FSMC_D[15:0] valid data after FSMC_CLK low	-	6	ns
$t_{su(NWAITV-CLKH)}$	FSMC_NWAIT valid before FSMC_CLK high	7	-	ns
$t_{h(CLKH-NWAITV)}$	FSMC_NWAIT valid after FSMC_CLK high	2	-	ns
$t_{d(CLKL-NBLH)}$	FSMC_CLK low to FSMC_NBL high	1	-	ns

1. $C_L = 15$ pF.

2. Preliminary values.

Figure 23. Standard I/O input characteristics - CMOS port

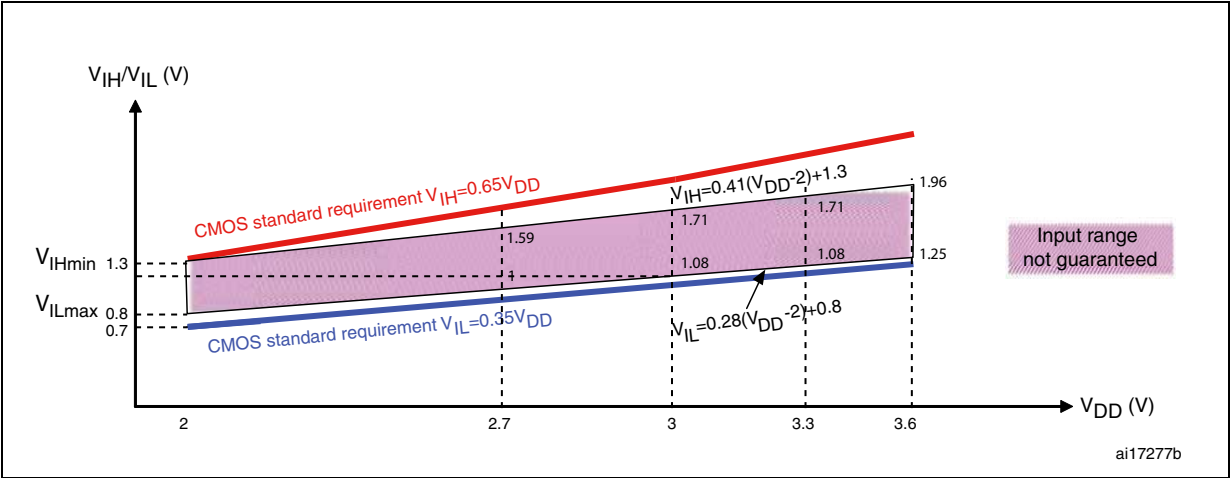


Figure 24. Standard I/O input characteristics - TTL port

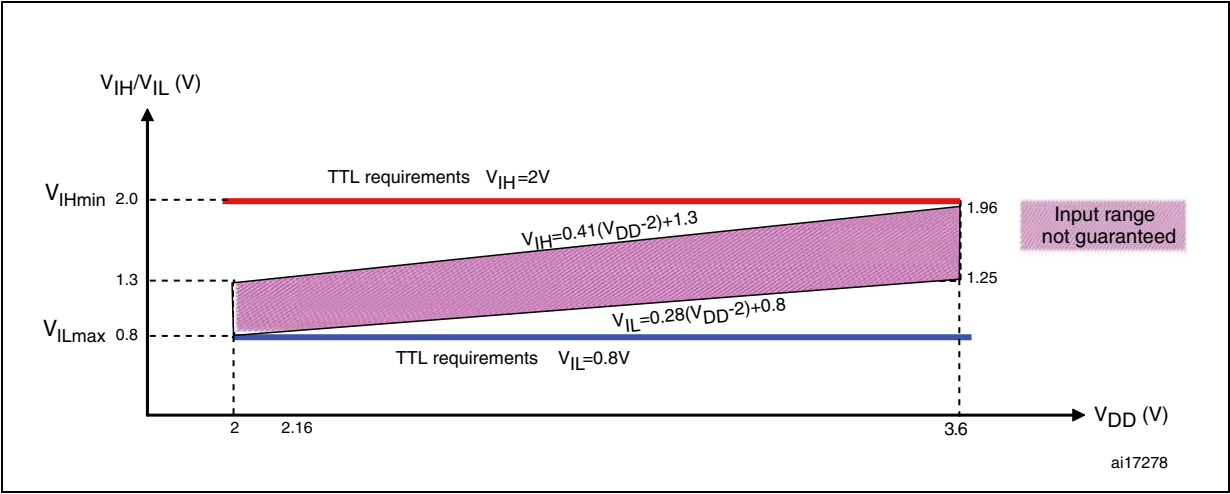
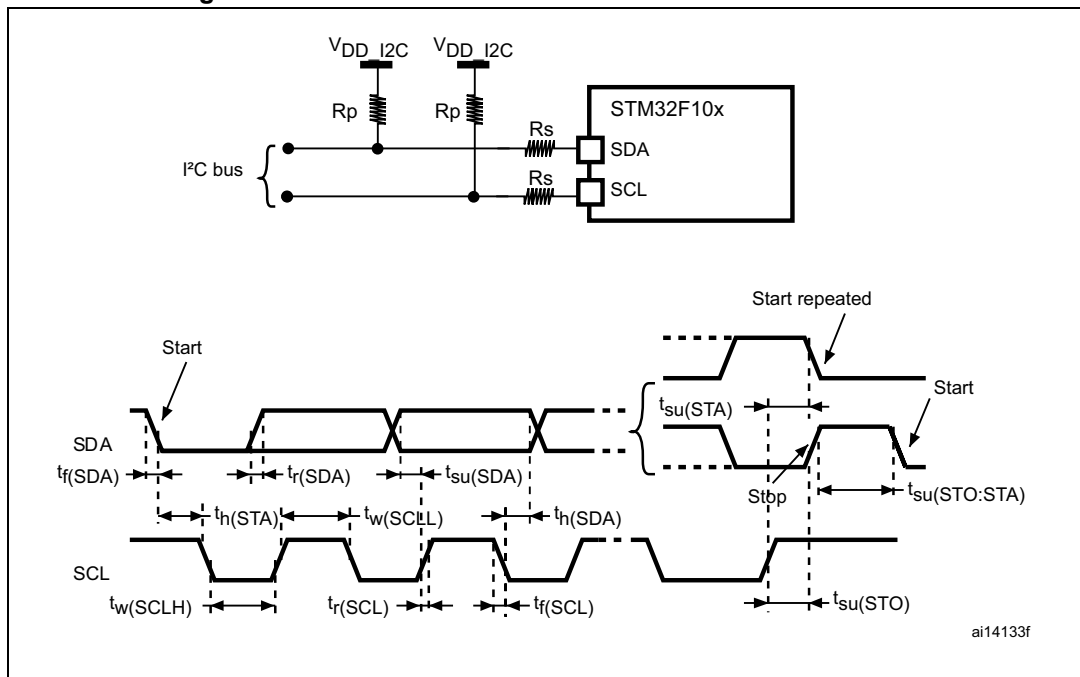


Figure 29. I²C bus AC waveforms and measurement circuit

1. Measurement points are done at CMOS levels: $0.3V_{DD}$ and $0.7V_{DD}$.

Table 49. SCL frequency ($f_{PCLK1} = 24 \text{ MHz}$, $V_{DD} = 3.3 \text{ V}$)⁽¹⁾⁽²⁾

$f_{SCL} \text{ (kHz)}^{(3)}$	I2C_CCR value
	$R_P = 4.7 \text{ k}\Omega$
400	0x8011
300	0x8016
200	0x8021
100	0x0064
50	0x00C8
20	0x01F4

1. R_P = External pull-up resistance, f_{SCL} = I²C speed,
2. For speeds around 400 kHz, the tolerance on the achieved speed is of $\pm 2\%$. For other speed ranges, the tolerance on the achieved speed $\pm 1\%$. These variations depend on the accuracy of the external components used to design the application.
3. Guaranteed by design, not tested in production.

Table 57. LQFP144 - 144-pin, 20 x 20 mm low-profile quad flat package mechanical data

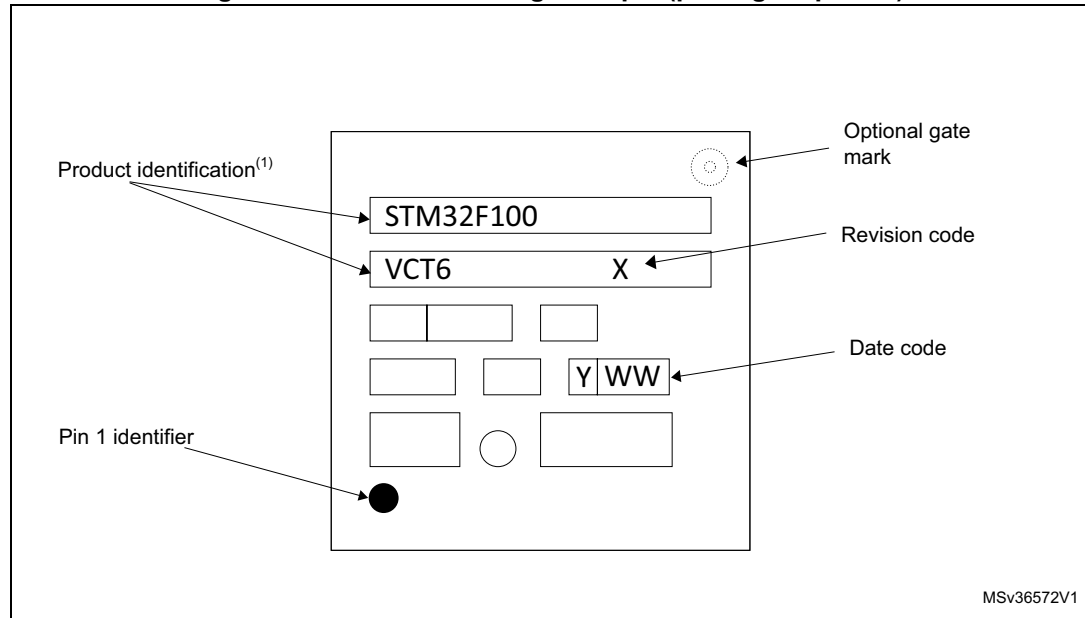
Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	-	-	1.600	-	-	0.0630
A1	0.050	-	0.150	0.0020	-	0.0059
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571
b	0.170	0.220	0.270	0.0067	0.0087	0.0106
c	0.090	-	0.200	0.0035	-	0.0079
D	21.800	22.000	22.200	0.8583	0.8661	0.8740
D1	19.800	20.000	20.200	0.7795	0.7874	0.7953
D3	-	17.500	-	-	0.6890	-
E	21.800	22.000	22.200	0.8583	0.8661	0.8740
E1	19.800	20.000	20.200	0.7795	0.7874	0.7953
E3	-	17.500	-	-	0.6890	-
e	-	0.500	-	-	0.0197	-
L	0.450	0.600	0.750	0.0177	0.0236	0.0295
L1	-	1.000	-	-	0.0394	-
k	0°	3.5°	7°	0°	3.5°	7°
ccc	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Device marking for LQFP100

The following figure shows the device marking for the LQFP100 package.

Figure 43.LQFP100 marking example (package top view)

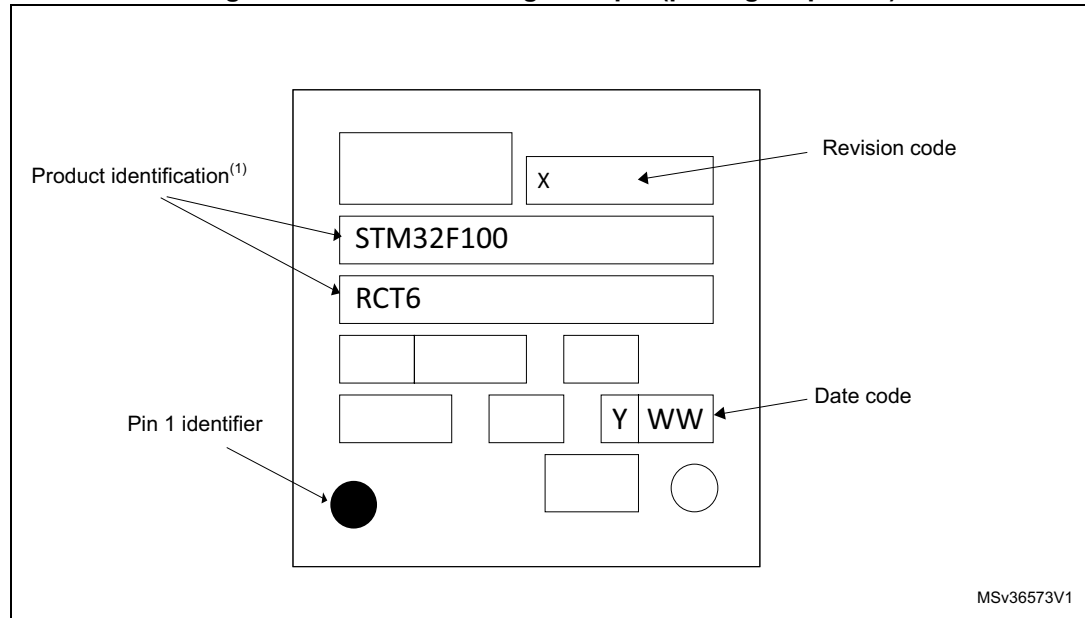


1. Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.

Device marking for LQFP64

The following figure shows the device marking for the LQFP64 package.

Figure 46.LQFP64 marking example (package top view)



1. Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.

Using the values obtained in [Table 60](#) T_{Jmax} is calculated as follows:

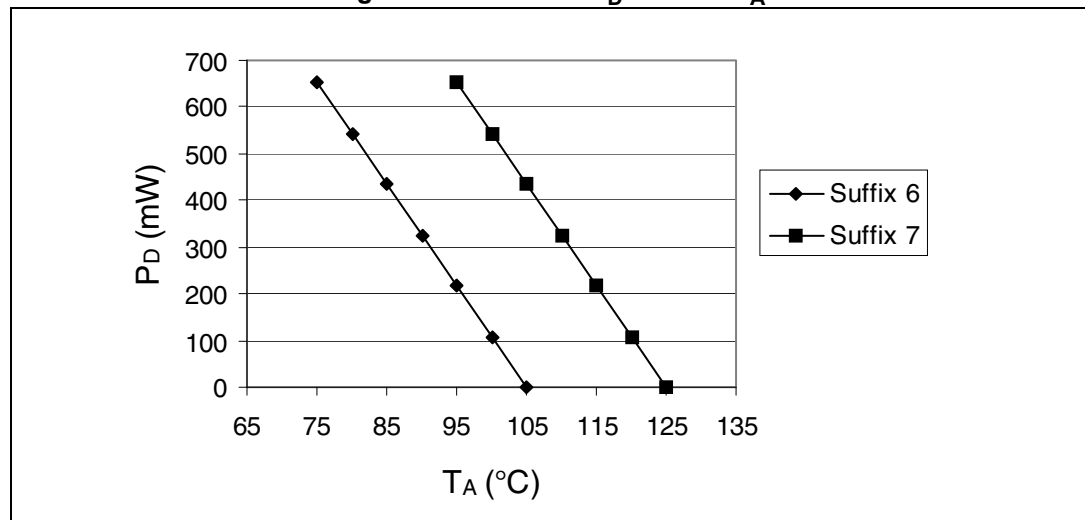
– For LQFP100, 40 °C/W

$$T_{Jmax} = 115\text{ °C} + (40\text{ °C/W} \times 134\text{ mW}) = 115\text{ °C} + 5.4\text{ °C} = 120.4\text{ °C}$$

This is within the range of the suffix 7 version parts ($-40 < T_J < 125\text{ °C}$).

In this case, parts must be ordered at least with the temperature range suffix 7 (see [Table 61: Ordering information scheme](#)).

Figure 47. LQFP100 P_D max vs. T_A



8 Revision history

Table 62. Document revision history

Date	Revision	Changes
09-Oct-2008	1	Initial release.
31-Mar-2009	2	I/O information clarified on page 1. Table 5: High-density STM32F100xx pin definitions modified. Figure 5: Memory map on page 26 modified. Note modified in Table 13: Maximum current consumption in Run mode, code with data processing running from Flash and Table 15: Maximum current consumption in Sleep mode, code running from Flash or RAM. Table 20: High-speed external user clock characteristics and Table 21: Low-speed user external clock characteristics modified. ACCHSI max values modified in Table 24: HSI oscillator characteristics. Note modified in Table 13: Maximum current consumption in Run mode, code with data processing running from Flash and Table 15: Maximum current consumption in Sleep mode, code running from Flash or RAM. Figure 10, Figure 11 and Figure 12 show typical curves (titles changed). Small text changes.
01-Sep-2010	3	Major revision of whole document. Added LQFP144 package and additional peripherals (SPI3, UART4, UART, TIM5, 12, 14, 13, FSMC).
18-Oct-2010	4	Updated Power consumption data in Table 13 to Table 16 Updated Section 5.3.11: EMC characteristics on page 68
11-Apr-2011	5	Added Section 2.2.6: LCD parallel interface on page 13 In Table 4 on page 24 moved TIM15_BKIN and TIM17_BKIN from remap to default column. Updated description of PA3, PA5 and PF6 to PF10. Updated footnotes below Table 6: Voltage characteristics on page 37 and Table 7: Current characteristics on page 38 Added VBAT values in Table 16: Typical and maximum current consumptions in Stop and Standby modes on page 44 Updated tw min in Table 20: High-speed external user clock characteristics on page 50 Updated startup time in Table 23: LSE oscillator characteristics (fLSE = 32.768 kHz) on page 53 Added HSI clock accuracy values in Table 24: HSI oscillator characteristics on page 54 Updated FSMC Synchronous waveforms and timings on page 62 Updated Table 43: I/O static characteristics on page 71 Added Section 5.3.13: I/O current injection characteristics on page 70 Corrected TTL and CMOS designations in Table 44: Output voltage characteristics on page 74